

## Estimate of density-of-states changes with disorder in A-15 superconductors\*

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Data are presented which show that the density of states changes dramatically, as does  $T_c$ , in both Nb<sub>3</sub>Sn and Nb<sub>3</sub>Ge samples which were disordered by  $\alpha$ -particle irradiation. The density of states is derived from the strong-coupling modifications to the theory of type-II superconduction along with measurements of  $(dH_{c2}/dT)_{T_c}$  and the residual normal-state resistance  $\rho_0$ .

### I. INTRODUCTION

Various models<sup>1</sup> have been proposed for the rapid depression of  $T_c$  with disorder found in A-15 superconductors, and also in other  $d$ -band superconductors such as Nb.<sup>2-4</sup> The behavior of the density of states and its relationship of  $T_c$  and disorder is crucial to this problem.

In this paper we use a thermodynamic method to estimate changes in the density of states  $N$  as a function of disorder in A-15 materials. Although there are some possible problems with the absolute accuracy of the method, changes in  $N$  of the order of a factor of 4 are observed as  $T_c$  changes from near 20 K to about 4 K, and the method nicely demonstrates these large changes in  $N$ .

As far as we know, there is no actual theory for how disorder affects the density of states. This question was considered by Crow *et al.*<sup>2</sup> with regard to drastic changes in the  $T_c$  of transition-metal superconductors when they were made very disordered by deposition onto cryogenic substrates, and there has been further discussion recently for A-15 superconductors by Dynes and Varma.<sup>4</sup> In the paper of Crow *et al.*,<sup>2</sup> a plausibility argument was given for density-of-states smearing by use of the uncertainty relationship

$$\Delta E \Delta t \sim \hbar. \quad (1)$$

For mean free paths  $l$  of the order of interatomic spacings, it is reasonable to expect significant smearing. We will consider this problem in more detail later. In the case of the A-15 superconductors where extremely sharp structure is expected in the density of states near the Fermi level, a significant change with  $l$  can be expected. Since  $T_c$  is expected to correlate with  $N$ ,<sup>2,4</sup> changes with  $T_c$  are expected with decreased  $N$  due to a decreased  $l$ . The measurements presented here show this effect. We emphasize that this approach based on  $N$  decreasing with  $l$ , implies that the effects due to defects are additive and are reflected in the normal-state resistivity  $\rho_0$ . The detailed

nature of the defect is relatively unimportant except for the change in  $\rho_0$  which determines the effect on  $N$ .<sup>5</sup>

### II. METHOD

To estimate changes in  $N$  with changes in  $\rho_0$ , we first consider a phenomenological analysis for  $N$  in terms of  $(dH_{c2}/dT)_{T_c}$  and  $\rho_0$ . We caution that this analysis does not adequately account for strong coupling, as will be made clear in Sec. III. At 0 K, one can equate the gap energy from the BCS theory to the condensation energy

$$\frac{1}{2}N^*\Delta^2 = H_c^2(0)/8\pi, \quad (2)$$

where  $N^*$  is the specific-heat density of states.  $H_c(0)$  can then be related to  $H_{c2}(T)$ . Near  $T_c$ , we have

$$H_{c2} = \sqrt{2} \kappa H_c, \quad (3)$$

and if the Ginzburg-Landau parameter  $\kappa$  is slowly varying, we get

$$H'_{c2}(T_c) = - \left( \frac{dH_{c2}}{dT} \right)_{T_c} = -\sqrt{2} \kappa \left( \frac{dH_c}{dT} \right)_{T_c}.$$

Using the BCS relation  $H_c(T) = 1.74H_c(0)(1 - T/T_c)$ , we find

$$\left( \frac{dH_{c2}}{dT} \right)_{T_c} = -\sqrt{2} \kappa 1.74 \frac{H_c(0)}{T_c} \quad (4)$$

if  $\kappa$  is slowly varying. Assuming  $\Delta = \alpha T_c k_B$ , i.e.,  $\alpha$  depends on the coupling, then the density of states can be expressed as

$$N^* = \frac{(dH_{c2}/dT)_{T_c}^2}{\kappa^2 (1.74)^2 k_B^2 \alpha^2 8\pi} \frac{\text{erg}}{\text{cm}^3 \text{K}}, \quad (5)$$

where  $\kappa$  is given by

$$\kappa = 0.96 \lambda_L / \xi_0 + 0.7 \lambda_L / l,$$

where  $\lambda_L$  is the Landau penetration depth,  $\xi_0$  the coherence length, and  $l$  the electronic mean free path, or in terms of the resistivity  $\rho_0$  and  $\gamma$ ,

$$\kappa \sim 7.53 \times 10^3 \rho_0 \gamma^{1/2} (1 + 1.3l/\xi_0). \quad (6)$$

$\gamma$  is the specific-heat coefficient and is related to

the density of states through  $\gamma = \frac{2}{3}\pi^2 k_B^2 N(0)^*$ . Then,

$$N^* = [H'_{c2}(T_c)]^2 [\alpha^2 (1.74)^2 k_B^2 8\pi\gamma \\ \times (7.53 \times 10^3 \rho_0)^2 (1 + 1.3l/\xi_0)^2]^{-1}$$

and

$$\gamma = 2.16 \times 10^{-5} H'_{c2}(T_c) \frac{1}{\rho_0 (1 + 1.3l/\xi_0)} \frac{\text{erg}}{\text{cm}^3 \text{K}^2},$$

which can be written

$$\gamma = -6.5 \times 10^{-13} \left( \frac{dH_{c2}}{dT} \right)_{T_c} \frac{a_0^3}{\rho_0} \frac{1}{1 + 1.3l/\xi_0} \frac{\text{J}}{\text{mol K}^2}, \quad (7)$$

where  $a_0$  is the lattice spacing in Å. Hence, by measuring  $H'_{c2}(T_c)$  and dividing by  $\rho_0$  one can essentially get  $\gamma$ . The  $(1 + 1.3l/\xi_0)$  correction becomes important when  $l \sim \xi_0$ .

A better estimate of  $\gamma$  in the strong-coupling regime can be obtained by going to the microscopic theory. In the dirty limit, one can write

$$H'_{c2}(T_c) = (4/\pi) k_B c / eD,$$

where  $D = \frac{1}{3} v_F l$  is the diffusion constant,  $v_F$  is the Fermi velocity, and  $c$  is the velocity of light. Rainer and Bergmann<sup>6</sup> then show that in the strong coupling regime  $H'_{c2}(T_c)$  can be written

$$H'_{c2}(T_c) = 1.27 \eta c k_B / eD^*, \quad (8)$$

where  $\eta$  is a strong-coupling correction that depends on  $T_c/\langle\omega\rangle$ . For  $T_c/\langle\omega\rangle \sim 0.1$ , then  $\eta \sim 1.25$  and it goes to one as  $T_c/\langle\omega\rangle$  goes to zero. (Note that in their paper the factor  $eD^*$  is inverted.) The diffusion constant  $D^*$  is defined as  $D^* = D/(1 + \lambda)$ , where  $\lambda$  is the electron-phonon coupling coefficient. Then using the single-spin density of states and the expression for  $\rho = [2e^2 N(0) D]^{-1}$ , we can write

$$H'_{c2}(T_c) = 1.27 \eta e N \rho_0 (1 + \lambda) c k_B 2.$$

Hence, in terms of  $H'_{c2}$ , the electronic specific heat can be expressed as

$$\gamma = \frac{2}{3} \pi^2 N^* k_B^2 = [\pi^2 / 3 (1.27)] H'_{c2} k_B / \rho_0 \eta e c \\ = 2.2 \times 10^{-5} (H'_{c2} / \eta \rho_0) \text{erg/cm}^3 \text{K}^2,$$

where  $\rho_0$  is in  $\Omega \text{ cm}$ , and finally we get

$$\gamma = 6.5 \times 10^{-13} H'_{c2}(T_c) (a_0^3 / \rho_0 \eta) (\text{J/mol K}^2). \quad (9)$$

If  $l \geq \xi_0$  then we suppose the expression will have the  $(1 + 1.3l/\xi_0)$  factor found in the phenomenological analysis and hence

$$\gamma = 6.5 \times 10^{-13} H'_{c2} a_0^3 \left[ \rho_0 \eta \left( 1 + \frac{1.3l}{\xi_0^*} \right) \right]^{-1} \frac{\text{J}}{\text{mol K}^2}, \quad (10)$$

where now  $\xi_0^*$  is  $\xi_0/(1 + \lambda)$ .

### III. EXPERIMENTAL

The samples used in this study were  $\text{Nb}_3\text{Ge}$  and  $\text{Nb}_3\text{Sn}$  films prepared by electron-beam codeposition. Damage was provided by irradiating the samples with 2.5-MeV  $\alpha$  particles. After a relatively heavy irradiation, where  $T_c$  was depressed to the order of 4 K, both  $\rho_0$  and  $(dH_{c2}/dT)_{T_c}$  were determined.  $(dH_{c2}/dT)_{T_c}$  was determined by measuring the critical field as function of  $T$  near  $T_c$  in a 5-T superconducting magnet, with the sample gauge length normal to the field. To change  $T_c$ , the samples were annealed at various temperatures. At each new  $T_c$ ,  $(dH_{c2}/dT)_{T_c}$  and  $\rho_0$  were also measured.

### IV. DATA

In Fig. 1, we show plots of  $(dH_{c2}/dT)_{T_c}/\rho_0$  vs  $T_c$  for both  $\text{Nb}_3\text{Ge}$  and  $\text{Nb}_3\text{Sn}$  films. In Figs. 2 and 3, we show the variation of  $H'_{c2}(T_c)$  and  $\rho_0$  for each  $T_c$  reached after annealing. It is evident that  $H'_{c2}$  is slowly varying, with most of the changes in  $H'_{c2}(T_c)/\rho_0$  coming from the larger changes in  $\rho_0$ . The fact that  $dH_{c2}/dT$  is slowly varying as  $T_c$  decreases also implies that  $H_{c2}(0)$  decreases since by Eqs. (3) and (4) it can be seen that  $H_{c2}(0)$  is proportional to the product of  $H'_{c2}(T_c)$  and  $T_c$ . Note that in the extreme dirty limit,  $\gamma$  is related to  $H'_{c2}(T_c)/\rho_0$ , since  $l/\xi_0$  becomes small. However, in the case of  $\text{Nb}_3\text{Sn}$ , where for clean films  $l \geq \xi_0^*$ , and even in the case of  $\text{Nb}_3\text{Ge}$ , where in the cleanest films  $l \sim 5\xi_0^*$  one must include the  $(1 + 1.3l/\xi_0^*)$  correction. An estimate of  $l$  can be obtained from  $\rho_0$  and various estimates can be made of  $\xi_0^*$ . We assume that for  $\rho_0 \sim 150 \mu\Omega \text{ cm}$ ,

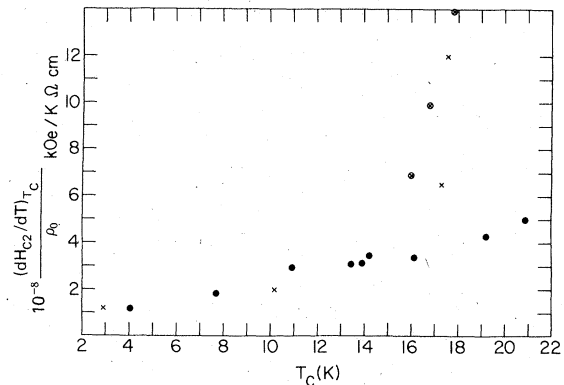


FIG. 1.  $\text{Nb}_3\text{Ge}$ —● is represented by three sets of data. In each case initially high- $T_c$  samples, 19–21 K, were measured, radiation damaged, and recovered by subsequent annealing. The  $\text{Nb}_3\text{Sn}$ — $\times$  data was acquired in the same manner except for three  $\text{Nb}_3\text{Sn}$ — $\otimes$  samples which were only measured “as grown.”

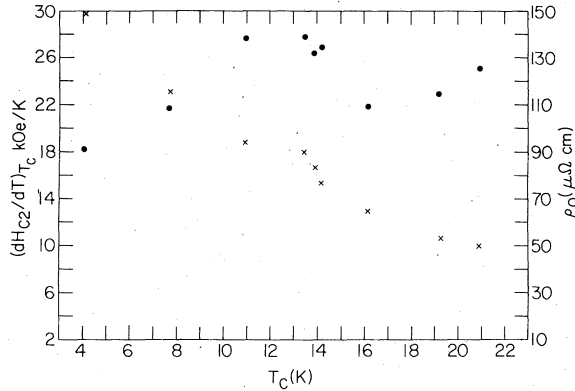


FIG. 2. Raw data for  $\text{Nb}_3\text{Ge}$  used to construct Fig. 1.  $(dH_{c2}/dT)_{T_c}$  —● is seen to be relatively constant with most of the variation in  $\rho_0$ —x. The complimentary points for each sample are vertically opposite each other.

$l \sim 5 \text{ \AA}$ , and thus,  $l\rho_0 \sim 750 \text{ \AA } \mu\Omega \text{ cm}$ . In Fig. 4, we show  $\gamma\eta$  for  $\text{Nb}_3\text{Sn}$  and  $\text{Nb}_3\text{Ge}$  assuming that  $\xi_0^* \sim 50 \text{ \AA}$  in Eq. (10)

#### V. DISCUSSION

The essential philosophy in presenting these data is not to get accurate numerical values of  $\gamma$  or  $N$  since there are some problems with the method which will be discussed below. The main point we wish to emphasize is the large change in  $\gamma$  with the transition temperature of the superconductor. It can be seen that in a qualitative way  $\gamma$  depends linearly on  $T_c$ . Excluding the regions where  $\rho_0$  is very small, i.e., very long  $l$ , or where  $\rho_0$  is very large, i.e.,  $N$  and  $T_c$  are saturated, it can be seen

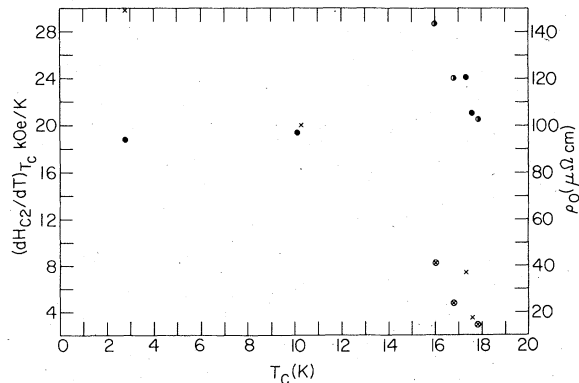


FIG. 3. Raw data for  $\text{Nb}_3\text{Sn}$  used to construct Fig. 1.  $(dH_{c2}/dT)_{T_c}$  —● is relatively constant compared to variation in  $\rho_0$ —x. The complimentary points for each sample are vertically opposite each other. ● represents  $(dH_{c2}/dT)_{T_c}$  for "as grown" samples and ⊗ represents corresponding values of  $\rho_0$ .

that since  $H_{c2}^l(T_c)$  is slowly varying,  $\gamma$  goes approximately as  $1/\rho_0$ . This can be understood on the basis of a simple model which emphasizes the smearing of the density of states as  $l$  gets smaller.

Consider a sharp structure in the density of states near the Fermi level  $E_F$  with a width of about 100 K. It is argued that  $N$  will decrease if the uncertainty in the energy  $\Delta E$  approaches about 100 K. From the uncertainty relationship, a length  $l$  can be derived from

$$\Delta E \Delta t = \Delta E = l/v_F = \hbar$$

for  $\Delta E = 100 \text{ K}$  and  $v_F = 10^7 \text{ cm/sec}$ ,  $l \sim 100 \text{ \AA}$ . Hence, when  $l$  is of the order of  $100 \text{ \AA}$ , smearing of  $N$  can be expected. Since  $\Delta E$  goes as  $1/l$ , it is also true that  $\Delta E \propto \rho_0$ . If one assumes a constant number of states in the density-of-states peak near  $E_F$ , then the area of the curve becomes  $N\Delta E$  for small  $l$ . Since  $\Delta E \propto \rho_0$ , we have  $N \propto 1/\rho_0$ . Of course, this analysis is only qualitative in nature and no attempt has been made to consider  $N^*(0) = (1 + \lambda)N(0)$ .

It should be mentioned that the relatively large initial changes of  $\gamma$  with  $T_c$  shown in Fig. 4 for the case of  $\text{Nb}_3\text{Sn}$  might be explained by the recent argument of Nettle and Thomas,<sup>7</sup> which indicates that in the theory of superconductivity the peak density of states at the Fermi level must be averaged over energies of the order of the phonon cutoff, and  $T_c$  would depend on this average  $N$ , i.e.,  $\bar{N}$ . We would then expect  $\gamma$  which goes as  $N^*(0) = N(0)(1 + \lambda)$  to change more rapidly with disorder than  $T_c$  which is proportional to  $\bar{N}$ , since  $N(0)$  is a sharper function than  $\bar{N}$  and would be more easily affected by small amounts of disorder.

It is of some interest to calculate the value of  $\gamma$  at  $T_{c0}$  for both  $\text{Nb}_3\text{Sn}$  and  $\text{Nb}_3\text{Ge}$ . We find in  $\text{Nb}_3\text{Ge}$  that at 20 K,  $\gamma\eta \sim 35 \text{ (mJ/mol K}^2\text{)}$ , or  $\gamma = 28$

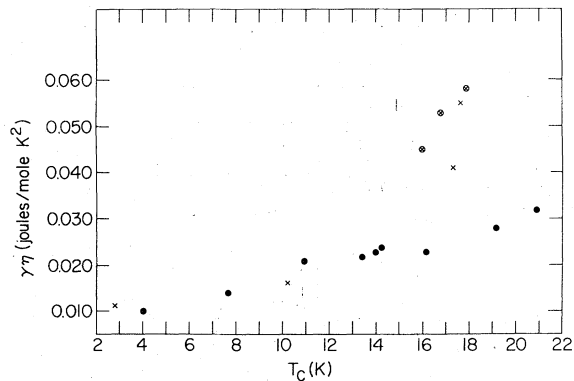


FIG. 4.  $\gamma\eta$  is shown for  $\text{Nb}_3\text{Ge}$ —● and  $\text{Nb}_3\text{Sn}$ —x, ⊗ according to Eq. (10).

(mJ/mol K<sup>2</sup>). In the case of Nb<sub>3</sub>Sn which is *not* in the dirty limit, the values are more uncertain. If we assume  $\xi_0^* \sim 50 \text{ \AA}$ , then for  $T_c = 17.8$ ,  $\gamma\eta \sim 60$  (mJ/mol K<sup>2</sup>) or  $\gamma \sim 48$  (mJ/mol K<sup>2</sup>). The specific-heat values are<sup>8</sup>  $\sim 52$  (mJ/mol K<sup>2</sup>) for Nb<sub>3</sub>Sn and<sup>9</sup>  $\sim 24$  (mJ/mol K<sup>2</sup>) for Nb<sub>3</sub>Ge. We think this agreement is reasonable. In the clean limit, the problem is very difficult since  $\xi_0^*$  is not really known.

We also briefly mention that there are some other problems with getting  $\gamma$  from  $H'_{c2}(T_c)$ . In the regime where  $l \sim a$ , and there is the possibility of saturation in the resistivity, it is not clear how  $H_{c2}$  is related to  $l$  and the resistivity. Finally, it has been assumed there is no paramagnetic limiting, which is expected to make only a very small error in  $H'_{c2}(T_c)$ .<sup>10</sup>

## VI. SUMMARY

Results are presented which show that the density of states decreases in A-15 samples with different  $T_c$ 's owing to different states of disorder. This change is quite sizable and appears to be about a factor of four from the undamaged  $T_{c0}$  to the lowest  $T_c$  caused by  $\alpha$ -particle damage. It can also be seen that to first order, the density of states goes inversely as the residual resistance. This view leads one to believe that any "defect" which affects the scattering time and  $\rho_0$  will change  $N$  and  $T_c$ .

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